NSN 5961-01-388-0099

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-388-0099 **Inclosure Material:** Ceramic **Overall Length:** Between 0.160 inches and 0.180 inches **Terminal Length:** 0.0375 inches **Overall Height:** Between 0.070 inches and 0.085 inches **Overall Width:** Between 0.130 inches and 0.150 inches **Function For Which Designed:** Transient suppressor and zener diode **Mounting Method: Terminal Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 26.7 breakdown voltage, dc and 29.5 breakdown voltage, dc **Current Rating Per Characteristic:** 15.40 amperes source cutoff current universal **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius ambient air **Special Features:** The ca suffix after the part number indicates that the part is a bidirectional part; junction pattern arrangement: pn **Terminal Type And Quantity:** 2 tab, solder lug Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: